

Technical Data Sheet

YDS-A32VBWK

8.00mm (0.32 inch), Red LED Display Single Digit 7-segment LED Display

Features

- High reliability
- Low power consumption
- Excellent characters appearance
- Evenly lighted segments
- Wide viewing angle
- Easy mounting on PCB or sockets
- I.C. compatible
- RoHS compliant

Descriptions

- The YDS-A32VBWK is a 8.00mm (0.32inch) digit height seven-segment LED display.
- The display provides excellent reliability in bright ambient light.
- The device is as either common anode or common cathode.
- The device is made with white diffused segments and black surface.

Applications

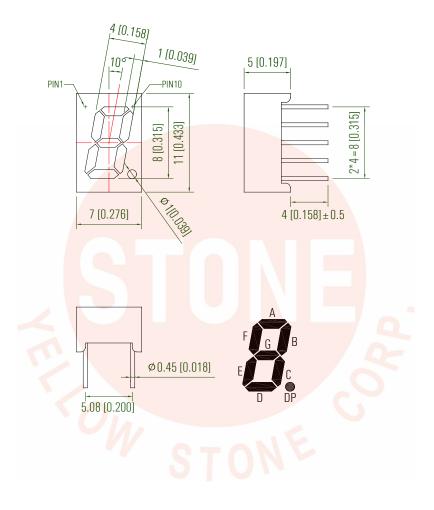
- Home and smart appliances
- Instrument panels
- Display time and digital combination
- Test and measurement equipment
- Control units

Device Selection Guide

| Part No. | Emitting Color | Circuit Common | | |
|-------------|----------------|----------------|--|--|
| YDS-A32VBWK | Red | Common Anode | | |



Package Dimension

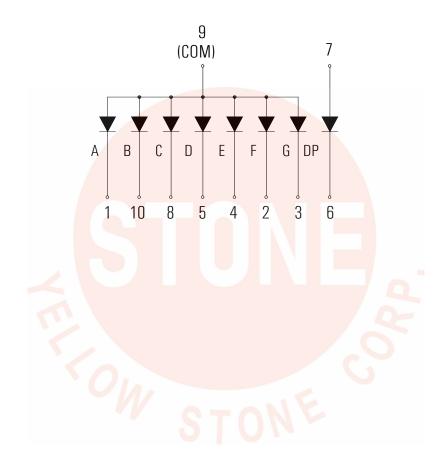


Notes:

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is \pm 0.25 mm (.010") unless otherwise noted.
- 3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.



Internal Circuit Diagram:



http://www.ystone.com.tw



Absolute Maximum Ratings at Ta=25°C

| Parameters | Symbol | Max | Unit mW | | |
|--|------------------|---------------|---------------------|--|--|
| Power Dissipation Per chip | P _d | 48 | | | |
| Peak Forward Current Per segment (1/10 Duty Cycle, 0.1ms pulse width) | I _{FP} | 40 | mA | | |
| Forward Current Per segment | I _F | 20 | mA | | |
| Reverse Voltage Per chip | V _R | 5 | V | | |
| Operating Temperature Range | T _{opr} | -40°C to + | -40°C to +80°C | | |
| Storage Temperature Range | T _{stg} | -40°C to +8 | -40°C to +85°C | | |
| Soldering Temperature | T _{sld} | 260°C for 5 S | 260°C for 5 Seconds | | |

Electrical Optical Characteristics at Ta=25°C

| Parameters | Symbol | Min. | Тур. | Max. | Unit | Test Condition |
|-----------------------------------|------------------|------|------|------|------|-----------------------|
| Average Luminous Intensity | lv - | 10.0 | 20.0 | | mcd | IF=10mA (Note a) |
| | | 20.0 | 40.0 | | mcd | IF=20mA (Note a) |
| Luminous Intensity Matching Ratio | I _{v-m} | | | 2:1 | 5 | IF=20mA |
| Peak Emission Wavelength | λρ | | 632 | | nm | IF=20mA |
| Dominant Wavelength | λd | (| 624 | | nm | IF=20mA (Note b) |
| Spectral Line Half-Width | Δλ | | 20 | | nm | IF=20mA |
| Forward Voltage Per Segment | V _F | | 2.0 | 2.4 | V | IF=20mA (Note c) |
| Reverse Current Per Segment | I _R | | | 50 | μA | VR=5V |
| | | | | | | • |

Notes:

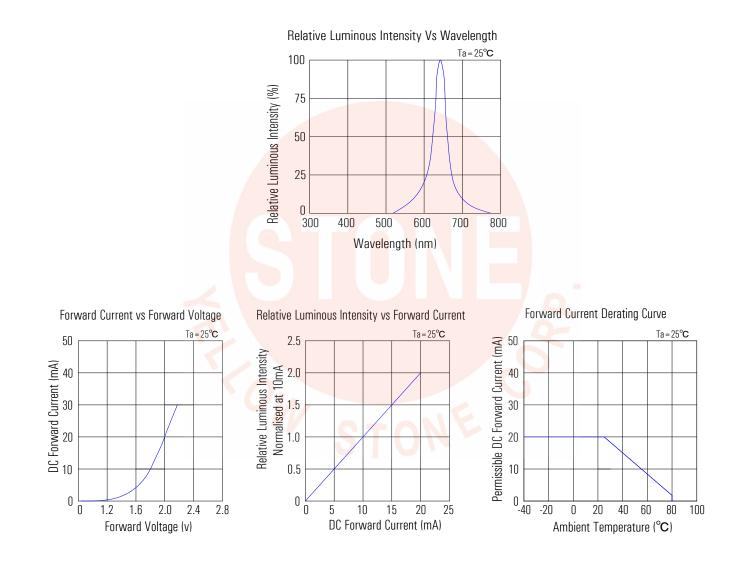
a. Luminous intensity is measured with a light sensor and filter combination that approximates the CIE eye-response curve. Tolerance of Luminous Intensity: \pm 10 %

b. The dominant wavelength (λ d) is derived from the CIE chromaticity diagram and represents the single wavelength which defines the color of the device.

c. Tolerance of Forward Voltage: ± 0.1V



Typical Electrical/Optical Characteristics Curves





Packing & Label Specifications:

